



## Efficient Tm:LiYF<sub>4</sub> Lasers at $\sim 2.3 \mu\text{m}$ : Effect of Energy-Transfer Upconversion

Pavel Loiko, Remi Soulard, Lauren Guillemot, Gurvan Brasse, Jean-Louis Doualan, Alain Braud, Aleksey Tyazhev, Ammar Hideur, Frédéric Druon, Patrice Camy

### ► To cite this version:

Pavel Loiko, Remi Soulard, Lauren Guillemot, Gurvan Brasse, Jean-Louis Doualan, et al.. Efficient Tm:LiYF<sub>4</sub> Lasers at  $\sim 2.3 \mu\text{m}$ : Effect of Energy-Transfer Upconversion. IEEE Journal of Quantum Electronics, 2019, 55 (6), pp.1-12. <10.1109/jqe.2019.2943477>. <hal-02991525>

**HAL Id: hal-02991525**

**<https://hal.science/hal-02991525v1>**

Submitted on 15 Nov 2020

**HAL** is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.



HAL Authorization

# Efficient Tm:LiYF<sub>4</sub> Lasers at ~2.3 $\mu\text{m}$ : Effect of Energy-Transfer Upconversion

Pavel Loiko, Rémi Soulard, Lauren Guillemot, Gurvan Brasse, Jean-Louis Doulan, Alain Braud, Aleksey Tyazhev, Ammar Hideur, Blandine Guichardaz, Frédéric Druon and Patrice Camy

**Abstract**—The  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition of Thulium ions ( $\text{Tm}^{3+}$ ), which features laser emission at ~2.3  $\mu\text{m}$  is studied in details. We revise the conditions for efficient laser operation using a rate-equation model accounting for the ground-state bleaching, cross-relaxation and energy-transfer upconversion (ETU). We show that ETU has a crucial role in reaching more than unity pump quantum efficiency (QY) for ~2.3  $\mu\text{m}$  Tm lasers based on highly-doped crystals. A Ti:Sapphire pumped quasi-continuous-wave 3.5 at.% Tm:LiYF<sub>4</sub> laser generated 0.73 W at 2306 nm with a record-high slope efficiency of 47.3% (versus the absorbed pump power) featuring a QY of 1.27. Diode-pumping of this crystal yielded a peak output power of >2 W. The first 2.3  $\mu\text{m}$  Tm waveguide laser is also reported based on Tm:LiYF<sub>4</sub> epitaxial layers with even higher doping of 6.2 at.% generating 0.23 W with a slope efficiency of 19.8%. The spectroscopic properties of Tm:LiYF<sub>4</sub> relevant for the ~2.3  $\mu\text{m}$  laser operation are revised as well.

**Index Terms**—Solid-state lasers, laser transitions, mid-infrared, spectroscopy.

## I. INTRODUCTION

NOWADAYS, there is a great demand of mid-infrared (MIR) laser sources emitting at wavelengths around ~2.3  $\mu\text{m}$ . In this spectral range, the absorption lines of such atmospheric pollutants as hydrogen fluoride (HF), carbon monoxide (CO), methane (CH<sub>4</sub>) and formaldehyde (H<sub>2</sub>CO) are located [1-5]. Such MIR emission falls into the 2.0–2.4  $\mu\text{m}$  atmospheric window, the so-called K band. Thus, wavelength-tunable ~2.3  $\mu\text{m}$  lasers are used for gas sensing in the atmosphere [1,3,5] or

during the combustion experiments [2]. They are also relevant for non-invasive glucose measurements [6].

There exist several possibilities to achieve laser emission at ~2.3  $\mu\text{m}$ . The first option is to use transition-metal-ion doped II-VI materials, i.e.,  $\text{Cr}^{2+}:\text{ZnS}$  or  $\text{Cr}^{2+}:\text{ZnSe}$  [7,8]. However, the synthesis of zinc chalcogenide crystals and ceramics with high optical quality is complicated and, moreover, these gain media cannot be directly pumped by laser diodes. The second option is the use of semiconductor materials (GaInAs on InP or GaInAsSb on GaSb) [9-12], in Vertical-Cavity Surface-Emitting Lasers (VCSELs) with a sophisticated design.

An easier way to generate the ~2.3  $\mu\text{m}$  laser emission is to use optically-pumped dielectric materials (crystals or glasses) doped with trivalent Thulium ions ( $\text{Tm}^{3+}$ ).  $\text{Tm}^{3+}$  possesses an electronic configuration of  $[\text{Xe}]4f^{12}$  and it is well-known for its near-infrared (NIR) laser emission at ~2  $\mu\text{m}$  due to the  $^3\text{H}_4 \rightarrow ^3\text{H}_6$  transition [13], see Fig. 1(a).  $\text{Tm}^{3+}$ -doped materials are typically pumped at ~0.8  $\mu\text{m}$  (to the  $^3\text{H}_4$  level), e.g., using Ti:Sapphire lasers or high-power AlGaAs laser diodes. There exist a very efficient cross-relaxation (CR) process for adjacent  $\text{Tm}^{3+}$  ions which promotes this pumping scheme,  $\text{Tm}_1(^3\text{H}_4) + \text{Tm}_2(^3\text{H}_6) \rightarrow \text{Tm}_1(^3\text{F}_4) + \text{Tm}_2(^3\text{F}_4)$ . Thus, the pump quantum efficiency may approach 2 leading to reduced heat loading and high laser slope efficiency well exceeding the Stokes limit [14].

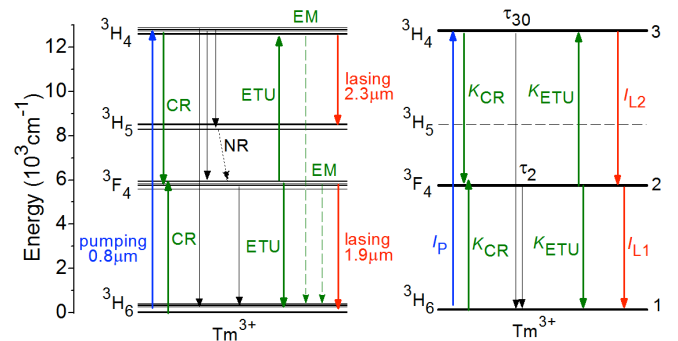


Fig. 1. (a) Simplified scheme of energy levels of  $\text{Tm}^{3+}$  ions in LiYF<sub>4</sub>: blue and red arrows – pump and laser transitions, respectively, black arrows – radiative relaxation, green arrows – non-radiative relaxation (NR), cross-relaxation (CR), energy-transfer upconversion (ETU), energy migration (EM); (b) equivalent scheme of energy levels for construction of rate equations. The Stark splitting for  $\text{Tm}^{3+}$  ions is according to [15].

The ~2.3  $\mu\text{m}$  MIR emission is related to less common  $\text{Tm}^{3+}$  transition,  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  [16], Fig. 1(a). Due to the small energy gap of about 2000  $\text{cm}^{-1}$  between the lower laser level ( $^3\text{H}_5$ ) and

Manuscript received February 1, 2019. This work was supported by French Agence Nationale de la Recherche (ANR) through the LabEx EMC3 project FAST-MIR; European Community funds FEDER and the Normandy region. (Corresponding author: Patrice Camy.)

R. Soulard, P. Loiko, L. Guillemot, G. Brasse, J.-L. Doulan, A. Braud and P. Camy are with the Centre de recherche sur les Ions, les Matériaux et la Photonique (CIMAP), UMR 6252 CEA-CNRS-ENSICAEN, Université de Caen, 6 Boulevard du Maréchal Juin, 14050 Caen Cedex 4, France (e-mail: remi.soulard@oca.eu; pavel.loiko@ensicaen.fr; lauren.guillemot@ensicaen.fr; gurkan.brass@ensicaen.fr; jean-louis.doulan@ensicaen.fr; alain.braud@ensicaen.fr; patrice.camy@ensicaen.fr).

A. Tyazhev and A. Hideur are with CORIA UMR6614, CNRS-INSU-Université de Rouen, Normandie Université, Avenue de l'université, BP. 12, 76801 Saint Etienne du Rouvray, France (e-mail: tyazheva@coria.fr; ammar.hideur@gmail.com).

B. Guichardaz is with the FEMTO-ST Institute, Route de Gray, 25030 Besançon Cedex, France (e-mail: blandine.guichardaz@femto-st.fr).

F. Druon is with the Laboratoire Charles Fabry, 2 avenue Augustin Fresnel 91127 Palaiseau, France (e-mail: frederic.druon@institutoptique.fr).

the lower-lying excited-state ( $^3F_4$ ), the former one is rapidly depopulated by the multi-phonon non-radiative (NR) relaxation, so that the ions are accumulated in the  $^3F_4$  metastable multiplet [17]. Thus, the  $\sim 2.3$   $\mu\text{m}$  laser transition representing a quasi-four-level laser scheme is not self-terminating.

A summary of bulk  $\sim 2.3$   $\mu\text{m}$  free-running and continuous-wave (CW) Tm lasers reported to date is shown in Table I. In early papers [16,18], pulsed laser operation has been achieved in Tm,Cr:Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub> and Tm,Cr:YAlO<sub>3</sub> oxide crystals (the Cr<sup>3+</sup> codoping enhanced the pump absorption efficiency) under flashlamp-pumping.

Further studies were performed with laser-pumping (using Alexandrite [19] and Ti:Sapphire [17,20] lasers) allowing for selective excitation to the  $^3H_4$  state. As gain materials, Tm<sup>3+</sup>-doped fluoride LiYF<sub>4</sub> and oxide Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub> or Lu<sub>3</sub>Al<sub>5</sub>O<sub>12</sub> crystals were employed. A Ti:Sapphire pumped Tm:LiYF<sub>4</sub> laser generated 0.22 W at 2.30  $\mu\text{m}$  with a slope efficiency of 15 % (versus the incident pump power, with 80% absorption) and a continuous tuning of the emission wavelength from 2.20 to 2.46  $\mu\text{m}$  was also demonstrated [18]. Slightly higher slope efficiency was reported [20] (Table I) whilst still being lower than the Stokes efficiency for the  $^3H_4 \rightarrow ^3H_5$  laser transition ( $\sim 34\%$ ).

The suitability of Yb<sup>3+</sup>,Tm<sup>3+</sup>-codoped fluoride crystals for laser emission at  $\sim 2.3$   $\mu\text{m}$  was analyzed theoretically in [21].

Regarding diode-pumping which may potentially allow for power scaling, the key results were achieved for Yb<sup>3+</sup>,Tm<sup>3+</sup>-codoped LiYF<sub>4</sub> crystals [22-24]. Here, the Yb<sup>3+</sup> ions were introduced to enhance the absorption efficiency when using InGaAs laser diodes emitting at  $\sim 0.98$   $\mu\text{m}$ . A diode-pumped Yb,Tm:LiYF<sub>4</sub> laser generated 0.45 W at 2.30-2.32  $\mu\text{m}$  (broadband emission) with a slope efficiency of 18% (with 65% pump absorption) [22].

TABLE I  
SUMMARY\* OF  $\sim 2.3$   $\mu\text{m}$  LASERS REPORTED SO FAR

Crystal	Pump**	$\lambda_p$ , $\mu\text{m}$	$P_{\text{out}}$ , W	$E_{\text{out}}$ , mJ	$\lambda_L$ , $\mu\text{m}$	$\eta$ , %	Ref.
Tm,Cr:Y <sub>3</sub> Al <sub>5</sub> O <sub>12</sub>	FL	—	—	—	2.32	—	[16]
	FL	—	—	150	2.32	0.4	[18]
Tm,Cr:YAlO <sub>3</sub>	FL	—	—	12	2.27, 2.35	—	[16]
Tm:LiYF <sub>4</sub>	AL	0.79	—	1.1	2.29–2.31	18	[19]
	TS	0.78	0.22	—	2.30	15	[17]
	TS	0.78	0.15	—	2.31	19	[20]
Tm:Y <sub>3</sub> Al <sub>5</sub> O <sub>12</sub>	AL	0.79	—	1.1	2.30–2.34	14	[19]
Tm:Lu <sub>3</sub> Al <sub>5</sub> O <sub>12</sub>	AL	0.79	—	1.0	$\sim 2.3$	13	[19]
Yb,Tm:LiYF <sub>4</sub>	LD	0.98	0.45	—	2.30–2.32	18	[22]
	LD	0.69+	0.62	—	$\sim 2.3$	7.9	[23]
		0.96					
Tm,Ho:LiYF <sub>4</sub>	LD	0.79	0.002	—	2.08+2.31	42	[24]
						***	
Tm:LiYF <sub>4</sub>	LD	0.79	0.01	—	$\sim 2.3$	10	[25]

\* $\lambda_p$  – pump wavelength,  $P_{\text{out}}$  and  $E_{\text{out}}$  – output power and pulse energy, respectively,  $\lambda_L$  – laser wavelength,  $\eta$  – slope efficiency. \*\*Pumping: FL – flashlamp; AL – Alexandrite laser; TS – Ti:Sapphire laser, LD – laser diode. \*\*\*For both Tm<sup>3+</sup> and Ho<sup>3+</sup> emissions.

Pulsed laser operation in the passively Q-switched (PQS) [20] and mode-locked (ML) [26,27] regimes has been also achieved for  $\sim 2.3$   $\mu\text{m}$  bulk Tm lasers. The first ML  $\sim 2.3$   $\mu\text{m}$  bulk Tm laser using Semiconductor Saturable Absorber

Mirror (SESAM) generated 94 ps pulses at 2305.9 nm [27]. Shorter ML pulses of 514 fs (emission bandwidth of  $>15$  nm) were achieved based on Kerr-lens mode-locking [26].

There also exist reports about  $\sim 2.3$   $\mu\text{m}$  Tm fiber lasers [28-32].

For the Tm<sup>3+</sup> ions, the lifetime of the  $^3H_4$  state (upper laser level for the  $\sim 2.3$   $\mu\text{m}$  transition) is subjected to quenching by different processes. Among them, multi-phonon NR relaxation which is strongly host-dependent, CR which raises fast with Tm<sup>3+</sup> doping and energy-migration (EM) which is relevant for certain materials and high Tm<sup>3+</sup> doping levels, Fig. 1(a). Thus, from the *host-material*-wise point of view, low-phonon hosts are preferred for  $\sim 2.3$   $\mu\text{m}$  lasers such as fluorides.

Among fluoride crystals, tetragonal lithium yttrium fluoride (LiYF<sub>4</sub>) has been considered for  $\sim 2.3$   $\mu\text{m}$  lasers [17,19,20]. This crystal is well-known for Tm<sup>3+</sup> doping and it provides highly efficient laser operation at the  $^3F_4 \rightarrow ^3H_6$  transition [33,34]. LiYF<sub>4</sub> features low maximum phonon energy,  $h\nu_{\text{ph}} = 446$  cm<sup>-1</sup> [35] diminishing the NR relaxation, good thermo-mechanical properties (the thermal conductivity is about 5–7 Wm<sup>-1</sup>K<sup>-1</sup>) [36] opening the ways for power scaling, low refractive index, broad transparency range and large range of available Tm<sup>3+</sup> concentrations [34]. The growth of LiYF<sub>4</sub> crystals by Czochralski method is well-developed [37]. When doped with Tm<sup>3+</sup> ions, the LiYF<sub>4</sub> crystals provide long (in the ms-range) lifetimes of the excited-states ( $^3H_4$  and  $^3F_4$ ) and anisotropic emission properties [38] leading to polarized laser output.

Now, let us consider the effect Tm<sup>3+</sup> *doping level* on the  $\sim 2.3$   $\mu\text{m}$  laser performance. At a glance, it should be kept low so that the shortening of the upper laser level ( $^3H_4$ ) lifetime by CR is weak. In the opposite case, the laser threshold will raise significantly. However, the doping cannot be too low to keep a reasonable pump absorption efficiency. As a result of such considerations,  $\sim 2.3$   $\mu\text{m}$  Tm:LiYF<sub>4</sub> lasers reported to date were based on crystals with low doping levels, about 1–2 at. % [17,19,20,25].

In the present paper, we aimed to investigate the effect of two relevant energy-transfer processes, namely, the CR and energy-transfer upconversion (ETU), Tm<sub>1</sub>( $^3F_4$ ) + Tm<sub>2</sub>( $^3F_4$ )  $\rightarrow$  Tm<sub>1</sub>( $^3H_6$ ) + Tm<sub>2</sub>( $^3H_4$ ) [39], on the performance of  $\sim 2.3$   $\mu\text{m}$  Tm:LiYF<sub>4</sub> lasers. As a result, we prove that the ETU can play a positive role in highly Tm<sup>3+</sup>-doped crystals leading to the laser slope efficiencies exceeding the Stokes limit (or, in other words, to pump quantum efficiency of more than unity).

## II. SPECTROSCOPY OF Tm:LiYF<sub>4</sub>

### A. Crystal growth

Bulk Tm:LiYF<sub>4</sub> crystals used for spectroscopic studies were grown by the Czochralski (Cz) method using undoped [001]-oriented LiYF<sub>4</sub> seeds. The growth temperature was  $\sim 780$  °C. The Tm<sup>3+</sup> doping concentration was 0.5, 1, 3, 5 and 10 at. %. Tetragonal LiYF<sub>4</sub> crystal (space group C<sub>4h</sub><sup>6</sup> – *I4<sub>1</sub>a*) is optically uniaxial (negative) and its optical axis is parallel to the crystallographic *c*-axis. The samples were thus oriented with respect to the *a* and *c* axes.

### B. ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$ $\text{Tm}^{3+}$ transition

The stimulated-emission (SE) cross-sections,  $\sigma_{\text{SE}}$ , for the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition of  $\text{Tm}^{3+}$  ions in  $\text{LiYF}_4$  were calculated using the F  chtbauer–Ladenburg (F-L) formula [40]:

$$\sigma_{\text{SE}}^i(\lambda) = \frac{\lambda^5}{8\pi^2 \tau_{\text{rad}} c} \frac{3W_j(\lambda)\beta(JJ')}{\sum_{j=\sigma,\pi,\alpha} \int \lambda W_j(\lambda) d\lambda}. \quad (1)$$

Here,  $W(\lambda)$  is the measured luminescence spectrum,  $n$  is the refractive index ( $n_o = 1.440$  and  $n_e = 1.462$ ) [41],  $c$  is the speed of light,  $\tau_{\text{rad}}$  is the radiative lifetime of the emitting state ( ${}^3\text{H}_4$ ),  $\beta(JJ')$  is the luminescence branching ratio. The index  $j$  indicates the light polarization. The transition  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  is of both electric dipole (ED) and magnetic dipole (MD,  $\Delta J = 0, \pm 1$ ) nature. Thus, for a uniaxial crystal, three principal light polarizations can be defined, i.e.,  $\sigma$  ( $\mathbf{E} \perp \mathbf{c}, \mathbf{k} \perp \mathbf{c}$ ),  $\pi$  ( $\mathbf{E} \parallel \mathbf{c}, \mathbf{k} \perp \mathbf{c}$ ) and  $\alpha$  ( $\mathbf{E} \perp \mathbf{c}, \mathbf{k} \parallel \mathbf{c}$ ) [42]. Here,  $\mathbf{E}$  and  $\mathbf{k}$  are the light polarization and propagation direction, respectively. Note that for purely ED transitions,  $\pi \equiv \alpha$ . This difference originates from the dependence of MD transition probability on the orientation of  $\mathbf{H}$  vector. A 1 at.%  $\text{Tm}:\text{LiYF}_4$  crystal was used to measure  $W(\lambda)$ . The results on  $\sigma_{\text{SE}}$  are shown in Fig. 2(a). The maximum  $\sigma_{\text{SE}} = 0.57 \times 10^{-20} \text{ cm}^2$  at 2305 nm for  $\pi$ -polarization. The bandwidth (FWHM) for the corresponding emission peak is 25.8 nm.

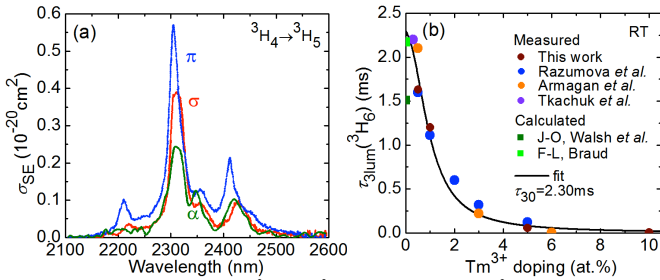


Fig. 2. Spectroscopy of the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition of  $\text{Tm}^{3+}$  ions in  $\text{LiYF}_4$ : (a) stimulated-emission (SE) cross-sections for the  $\pi$ ,  $\sigma$  and  $\alpha$  light polarizations; (b) luminescence lifetime of the  ${}^3\text{H}_4$  state  $\tau_{3\text{lum}}$  vs. the  $\text{Tm}^{3+}$  doping concentration: symbols – experimental data, curve – their fit with Eqs. (2)-(3),  $\tau_{30}$  is the intrinsic lifetime. All results correspond to room temperature.

For the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition, the upper laser level is  ${}^3\text{H}_4$ . The results on the  ${}^3\text{H}_4$  luminescence lifetimes  $\tau_{3\text{lum}}$  obtained in the present work and in the previous papers [38,43-46] are summarized in Fig. 2(b). The  $\tau_{3\text{lum}}$  decreases with the  $\text{Tm}^{3+}$  doping due to the CR effect. For the limit of very small doping concentration and, consequently, zero CR, the so-called intrinsic lifetime  $\tau_{30}$  can be deduced, see Fig. 1(b) [43]:

$$1/\tau_{3\text{lum}} = 1/\tau_{30} + W_{\text{CR}}. \quad (2)$$

Here,  $W_{\text{CR}}$  is the CR rate (in  $\text{s}^{-1}$ ). In Eq. (2), we do not account for other mechanisms of quenching of the  ${}^3\text{H}_4$  lifetime such as EM which is relevant for very high  $\text{Tm}^{3+}$  doping levels above 10 at.% [47]. One should distinguish  $\tau_{30}$  and the radiative lifetime  $\tau_{\text{rad}}$ . The latter is in general longer,  $\tau_{\text{rad}} \geq \tau_{30}$ , because it is an inverse of the probability of solely spontaneous

radiative transitions from the excited-state while  $\tau_{30}$  also includes the NR relaxation rate:  $1/\tau_{30} = 1/\tau_{\text{rad}} + W_{\text{NR}}$ . For  $\text{LiYF}_4$  featuring a relatively low maximum phonon frequency  $\hbar\nu_{\text{ph}}$ ,  $W_{\text{NR}}$  is almost zero for the  ${}^3\text{H}_4$  state [48]. Thus,  $\tau_{30} \approx \tau_{\text{rad}}$ . Note that this condition is typically not satisfied in oxide materials.

The CR rate is a function of  $\text{Tm}^{3+}$  concentration [49]:

$$W_{\text{CR}} = K_{\text{CR}} N_{\text{Tm}} = C_{\text{CR}} N_{\text{Tm}}^2, \quad (3)$$

where,  $K_{\text{CR}}$  and  $C_{\text{CR}}$  are the CR macro-parameter and the CR concentration-independent micro-parameter, respectively. By using Eqs. (2)-(3), we fitted the experimental data on  $\tau_{\text{lum}}({}^3\text{H}_4)$  yielding  $\tau_{30} = 2.3 \pm 0.1$  ms, Fig. 2(b). A classical way to calculate  $\tau_{\text{rad}}$  (and, thus,  $\tau_{30}$ ) theoretically is to use the Judd-Ofelt (J-O) theory. From the standard J-O calculations, Walsh *et al.* determined  $\tau_{\text{rad}}({}^3\text{H}_4) = 1.51$  ms [38]. This value seems to be underestimated because longer luminescence lifetimes were measured for low doped  $\text{Tm}:\text{LiYF}_4$  crystals [43,44]. Indeed, a simultaneous use of the reciprocity method (RM) and the F-L formula for transitions from the  ${}^3\text{H}_4$  state yielded  $\tau_{\text{rad}} = 2.2$  ms [46]. This value is in agreement with Fig. 2(b).

### C. Cross-relaxation and quantum efficiency

CR is an important process defining populations of the  $\text{Tm}^{3+}$  multiplets and, thus, the laser efficiency [14]. The CR rate was determined using Eqs. (2)-(3) based on the experimental luminescence lifetimes of the  ${}^3\text{H}_4$  state, Fig. 3(a). This figure is plotted in a double-log scale to illustrate the quadratic dependence of  $W_{\text{CR}}$  on  $N_{\text{Tm}}$ , Eq. (3). The best-fit  $C_{\text{CR}} = 0.25 \pm 0.03 \times 10^{-37} \text{ s}^{-1} \text{ cm}^3$ .

There exist another way to express the CR rate constant [50]:

$$W_{\text{CR}} = \frac{1}{\tau_{30}} \left( \frac{C_{\text{Tm}}}{C_0} \right)^2, \quad (4)$$

where,  $C_{\text{Tm}}$  is the doping level (in at.%) and  $C_0$  is the critical doping level which corresponds to a 2-fold decrease of the luminescence lifetime of the pump level ( ${}^3\text{H}_4$ ). For  $\text{Tm}:\text{LiYF}_4$ , we calculated  $C_0$  as 0.96 at.% (as 1 at.%  $\text{Tm}$  corresponds to the ion density of  $1.38 \times 10^{20} \text{ at/cm}^3$ , crystal density:  $\rho = 3.95 \text{ g/cm}^3$ ).

The pump quantum efficiency for the  ${}^3\text{F}_4$  state of  $\text{Tm}^{3+}$ -doped materials,  $\eta_{q1}$ , can exceed unity and approach 2 due to the CR effect (pumping at the  ${}^3\text{H}_6 \rightarrow {}^3\text{H}_4$  transition) [14,49]. Assuming no ground-state bleaching and no other processes such as ETU and EM, Honea *et al.* determined  $\eta_{q1}$  (a ratio of ions excited to the  ${}^3\text{F}_4$  state to the number of absorbed pump photons) as [50]:

$$\eta_{q1} = \frac{1/\tau_{30} + 2W_{\text{CR}} - (1/\tau_{\text{rad}})(1 - \beta_{32})}{1/\tau_{30} + W_{\text{CR}}}. \quad (5)$$

Here,  $\beta_{32}$  is the total luminescence branching ratio for the  ${}^3\text{H}_4 \rightarrow {}^3\text{F}_4 + {}^3\text{H}_5$  transitions (due to the strong NR relaxation from

the  $^3\text{H}_5$  state, both these transitions end up with the ions being at the  $^3\text{F}_4$  state). As explained above, for  $\text{Tm}:\text{LiYF}_4$ ,  $\tau_{30} \approx \tau_{3\text{rad}}$ . The results on  $\eta_{q1}$  are shown in Fig. 3(b). For very small  $\text{Tm}^{3+}$  doping,  $\eta_{q1}$  is limited by the  $\beta_{32}$  value. For more than 6 at.%  $\text{Tm}^{3+}$  doping, the theoretical pump quantum efficiency exceeding 1.95 (strong CR) is expected. The calculated results agree well with the estimation of So *et al.* based on analysis of the laser performance [39].

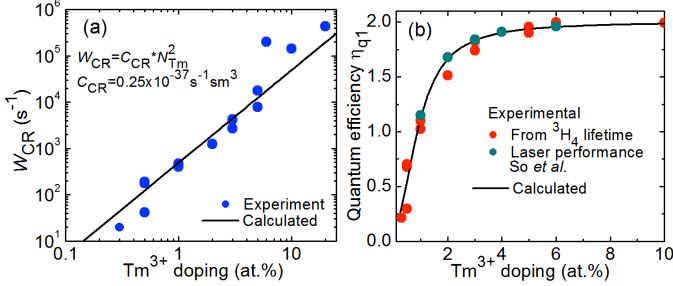


Fig. 3. Quantification of cross-relaxation in  $\text{Tm}:\text{LiYF}_4$ : (a) cross-relaxation rate  $W_{\text{CR}}$ : symbols – determined from the experimental data on  $\tau_{3\text{lum}}(^3\text{H}_4)$ , line – theoretical calculation using Eq. (3); pump quantum efficiency for the  $^3\text{F}_4$  state  $\eta_{q1}$ : symbols – determined from the experimental  $W_{\text{CR}}$  rates (this work) and from the laser performance [39], curve – theoretical calculation using Eq. (5). All data are plotted vs.  $\text{Tm}^{3+}$  doping concentration.

In Table II, we compared the parameters defining CR ( $\tau_{30}$ ,  $C_{\text{CR}}$  and  $C_0$ ) for several widespread  $\text{Tm}^{3+}$ -doped laser crystals [50–52]. Note that  $C_{\text{CR}}$  for  $\text{Tm}:\text{LiYF}_4$  is by order of magnitude smaller than in oxide crystals because of much longer intrinsic lifetime of the  $^3\text{H}_4$  state for this fluoride crystal.

TABLE II  
PARAMETERS\* OF CROSS-RELAXATION IN  $\text{Tm}^{3+}$ -DOPED CRYSTALS

Crystal	$\tau_{3\text{rad}}(^3\text{F}_4)$ , ms	$\tau_{30}(^3\text{F}_4)$ , ms	$C_{\text{CR}}$ , $10^{-37} \text{ cm}^6/\text{s}$	$C_0$ , at. %	Ref.
$\text{Tm}:\text{LiYF}_4$	$\sim 2.2$ [46]	2.3	0.25	0.96	This work
$\text{Tm}:\text{Lu}_2\text{O}_3$	0.69	0.35	1.25	0.53	[51]
$\text{Tm}:\text{Y}_3\text{Al}_5\text{O}_{12}$	1.44	0.54	3.95	0.50	[50]
$\text{Tm}:\text{KLu}(\text{WO}_4)_2$	$>> 0.20$	0.24	2.7	1.94	[52]

\* $\tau_{3\text{rad}}$  and  $\tau_{30}$  – radiative and intrinsic (unquenched) lifetimes of the  $^3\text{F}_4$   $\text{Tm}^{3+}$  state, respectively;  $C_{\text{CR}}$  – CR concentration-independent micro-parameter;  $C_0$  – critical  $\text{Tm}^{3+}$  doping level.

#### D. Energy-transfer upconversion

Energy-transfer upconversion in  $\text{Tm}:\text{LiYF}_4$ ,  $^3\text{F}_4 + ^3\text{F}_4 \rightarrow ^3\text{H}_4 + ^3\text{H}_6$ , is a phonon-assisted process which is detrimental for the  $\sim 1.9 \mu\text{m}$  laser transition [39] but can be useful for the  $\sim 2.3 \mu\text{m}$  one.

To quantify ETU, we excited  $\text{Tm}:\text{LiYF}_4$  crystals directly to the  $^3\text{F}_4$  state (at  $1.68 \mu\text{m}$ ) and monitored power dependence of luminescence from the  $^3\text{H}_4$  (at  $\sim 1.5 \mu\text{m}$ ) and  $^3\text{F}_4$  (at  $\sim 1.9 \mu\text{m}$ ) multiplets. The observation of the former emission is a direct evidence of ETU. From the ratio of integrated intensities of these emissions, we deduced the ratio of the populations  $N(^3\text{H}_4)/N(^3\text{F}_4)$ , see Fig. 4(a). This ratio was also calculated numerically using a rate-equation model accounting for the ground-state bleaching, CR, ETU and spatial distribution of the pump, as shown by the curves in Fig. 4(a). From such a modeling, we determined the ETU parameter  $K_{\text{ETU}}$  which amounted to  $3.5 \pm 1$ ,  $14.5 \pm 2$  and  $22 \pm 5 \times 10^{-20} \text{ cm}^3 \text{ s}^{-1}$  for 3, 4 and 5 at.%  $\text{Tm}$ -doping, respectively. As expected,  $K_{\text{ETU}}$  increases

with the  $\text{Tm}^{3+}$  concentration.

A summary of  $K_{\text{ETU}}$  values for  $\text{Tm}:\text{LiYF}_4$  reported to date is presented in Fig. 4(b). In [48,53],  $K_{\text{ETU}}$  was determined from luminescence-decay measurements. In [54], we determined it from the modeling of the laser performance and in [55], it was calculated theoretically. For  $\text{Tm}^{3+}$  doping below 6 at.% which is common for laser crystals, the results on  $K_{\text{ETU}}$  are in relative agreement with each other while for higher doping, a strong discrepancy is observed.

The concentration dependence of  $K_{\text{ETU}}$  has been previously expressed by a linear law using a concentration-independent micro-parameter  $C_{\text{ETU}}$  [49]:

$$K_{\text{ETU}} = C_{\text{ETU}} N_{\text{Tm}}. \quad (6)$$

In our case,  $C_{\text{ETU}} = 3.9 \pm 1 \times 10^{-40} \text{ cm}^6 \text{ s}^{-1}$  and it is by two orders of magnitude smaller than  $C_{\text{CR}}$ . However, the  $K_{\text{ETU}}$  parameters of  $\text{Tm}:\text{LiYF}_4$  are high enough to ensure efficient  $2.3 \mu\text{m}$  laser operation of this crystal, as will be shown below. Note the concentration dependence of  $K_{\text{ETU}}$  seems to be faster than linear and well fitted with a quadratic curve, Fig. 4(b).

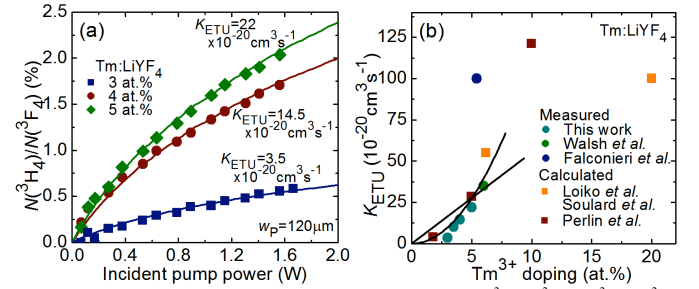


Fig. 4. Quantification of energy-transfer upconversion,  $^3\text{F}_4 + ^3\text{F}_4 \rightarrow ^3\text{H}_4 + ^3\text{H}_6$ , in  $\text{Tm}:\text{LiYF}_4$ : (a) ratios of the fractional populations of the  $^3\text{H}_4$  and  $^3\text{F}_4$   $\text{Tm}^{3+}$  multiplets for the  $1.68 \mu\text{m}$  excitation (pump spot radius:  $w_p = 120 \mu\text{m}$ ) vs. the incident pump power for various  $\text{Tm}^{3+}$  concentrations: symbols – experimental data, curves – their rate-equation modeling yielding  $K_{\text{ETU}}$  values; (b) summary of the ETU parameters reported to date, line and quadratic curve represent their possible concentration-dependences.

### III. BULK LASERS AT $\sim 2.3 \mu\text{m}$

#### A. Laser set-up

The laser experiments started using bulk  $\text{Tm}:\text{LiYF}_4$  crystal. The laser crystal was an *a*-cut 3.5 at.%  $\text{Tm}:\text{LiYF}_4$  having a cylindrical shape (diameter: 8.5 mm, length: 8.1 mm). The actual  $\text{Tm}^{3+}$  ion density  $N_{\text{Tm}} = 4.83 \times 10^{20} \text{ cm}^{-3}$ . Both its faces were polished to laser quality and antireflection (AR) coated for  $\sim 1.9 \mu\text{m}$ . The crystal was mounted on a Cu-holder using a silver thermal paste and it was passively cooled.

The scheme of the laser set-up is shown in Fig. 5. A hemispherical laser cavity was formed by a flat pump mirror (PM) coated for high transmission (HT) at the pump wavelength ( $T = 81\%$  at  $0.79 \mu\text{m}$ ) and at  $\sim 1.9 \mu\text{m}$  (the  $^3\text{F}_4 \rightarrow ^3\text{H}_6$   $\text{Tm}^{3+}$  emission) and for high reflection (HR) at  $\sim 2.3 \mu\text{m}$ , and a set of concave output couplers (OCs) with the radius of curvature of 100 mm and a transmission  $T_{\text{OC}}$  of 0.7%, 1.3% and 4.0% at  $2.3 \mu\text{m}$ . Due to the  $R = 95\%$  reflection from the OCs at the pump wavelength, the crystal was pumped in a



double-pass. Moreover, to suppress further the  $\sim 1.9 \mu\text{m}$  emission, all the OCs provided HT ( $T > 90\%$ ) at this wavelength. The geometrical cavity length was about 100 mm.

As the first pump source, we used a CW Ti:Sapphire laser (model 3900S, Spectra Physics) delivering 3.2 W at  $0.79 \mu\text{m}$  ( $M^2 \approx 1$ ). The pump power incident on the crystal was varied using a rotatory  $\lambda/2$  plate and a Glan-Taylor polarizer. The pump polarization in the crystal corresponded to  $\pi$ . The pump beam was focused by a spherical lens (focal length:  $f = 150 \text{ mm}$ ) resulting in a spot radius  $w_p$  of  $61 \mu\text{m}$  and a confocal parameter  $2z_R$  of 4.2 cm. The pump beam was mechanically modulated using a chopper (duty cycle: 1:2, pulse duration:  $\sim 10 \text{ ms}$ ) leading to quasi-CW pumping.

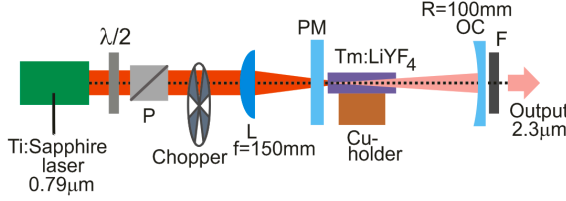


Fig. 5. Scheme of the  $\sim 2.3 \mu\text{m}$  Tm:LiYF<sub>4</sub> bulk laser pumped by a Ti:Sapphire laser:  $\lambda/2$  – rotatory half-wave plate, P – Glan-Taylor polarizer, L – lens, PM – pump mirror, OC – output coupler, F – cut-off filter.

The second pump source was a fiber-coupled AlGaAs laser diode (DILAS, fiber core diameter:  $105 \mu\text{m}$ , numerical aperture, N.A.: 0.22) emitting up to 28 W of unpolarized output at a wavelength of 793.2 nm (emission bandwidth:  $< 4 \text{ nm}$ ,  $M^2 \approx 46$ ). The pump beam was collimated and focused by a pair of spherical lenses ( $f = 50 \text{ mm}$  and  $150 \text{ mm}$ , respectively) resulting in  $w_p$  of  $150 \mu\text{m}$  and a Rayleigh length  $z_R$  of 5.7 mm. The pump beam was electrically modulated (duty cycle: 1:20, pulse duration:  $\sim 10 \text{ ms}$ ). Due to the strong divergence of the pump, during the second pump pass (after the reflection from the OC), the diameter of the pump beam in the crystal was  $\sim 1.5 \text{ mm}$  thus producing minor effect on inversion in the laser crystal. Consequently, the pumping was considered in single-pass.

The radius of the laser mode  $w_L$  in the crystal was estimated within the ABCD formalism to be  $70 \mu\text{m}$  (taking into account thermal lens in the crystal).

The laser emission spectra were measured using an optical spectrum analyzer (OSA, model AQ6375B, Yokogawa). The laser output was filtered from the residual pump using a cut-off filter (FEL 900, Thorlabs).

### B. Results: Ti:Sapphire pumping

First, we describe the results achieved using the Ti:Sapphire pumping. For all studied OCs, the laser operated solely at the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition with no emission at  $\sim 1.9 \mu\text{m}$ . The laser output was linearly polarized; the polarization was determined by the gain anisotropy ( $\pi$ ), see Fig. 2(a).

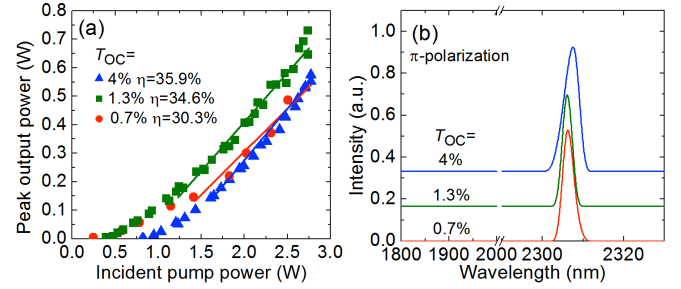


Fig. 6. Ti:Sapphire pumped  $\sim 2.3 \mu\text{m}$  Tm:LiYF<sub>4</sub> bulk laser: (a) input-output dependences,  $\eta$  – slope efficiency; (b) typical laser emission spectra. The laser polarization is  $\pi$ . The pumping is quasi-CW (duty cycle: 1:2).

The maximum peak output power was achieved using 1.3% OC, namely 0.73 W at 2306 nm with a slope efficiency  $\eta$  of 34.6% (vs. the incident pump power  $P_{\text{inc}}$ ). The input-output dependence was nonlinear close to the laser threshold (at  $P_{\text{inc}} = 0.40 \text{ W}$ ). Because of this, the fit for the determination of  $\eta$  was performed for pump powers of about 3 times higher than the threshold value, Fig. 6(a). The maximum optical-to-optical efficiency  $\eta_{\text{opt}}$  was 26.7%. For higher  $T_{\text{OC}} = 4\%$ , the laser operated with slightly higher slope efficiency (35.9%) whilst with lower peak output power of 0.55 W at 2305 nm and much higher laser threshold of 0.81 W. Further power scaling was limited by the available pump power. No thermal roll-over of the input-output dependences or crystal fracture were observed during the laser experiments.

The passive losses in the crystal were estimated to be 0.5% using the Findlay-Clay analysis [56].

The laser emission spectra for all OCs were similar, Fig. 6(b).

We have also studied true CW performance of this laser for the optimum 1.3% OC (i.e., when removing the chopper from the pump beam). The  $P_{\text{inc}}$  value was limited to approximately half of the available power,  $\sim 1.5 \text{ W}$ . The achieved CW output power was similar to the peak power achieved under quasi-CW regime. The maximum output power reached 0.24 W.

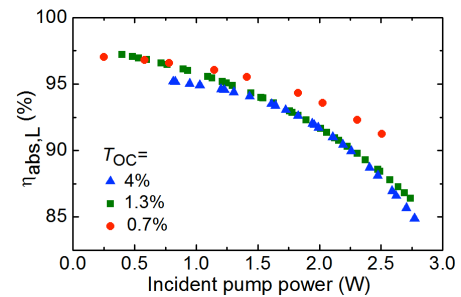


Fig. 7. Pump absorption under lasing conditions  $\eta_{\text{abs,L}}$  for 3.5 at.% Tm:LiYF<sub>4</sub> crystal (Ti:Sapphire pumping,  $w_p = 61 \mu\text{m}$ ).

The pump absorption under lasing conditions  $\eta_{\text{abs,L}}$  was determined by measuring the residual pump power after the OC with a short-pass filter. The results are shown in Fig. 7. The saturation of absorption was observed. In particular for 1.3% OC,  $\eta_{\text{abs,L}}$  decreased from 97.2% to 86.3% when the pump power increased from the laser threshold to its maximum value, i.e., from 0.40 to 2.74 W. For other OCs, a similar behavior was observed.

According to the measured pump absorption, the slope efficiency vs. the absorbed pump power  $P_{\text{abs}}$  for the 1.3% and 4% OCs reached 47.3% and 51.7%, respectively. Here, the fit of the input-output dependence was performed starting from the pump power well above the laser threshold as explained above. Thus, this work represents the best results in terms of output power and slope efficiency for any laser-pumped 2.3  $\mu\text{m}$  laser, cf. Table I.

### C. Results: diode-pumping

The results for diode-pumping are shown in Fig. 8. For all OCs, the laser generated a linearly polarized emission ( $\pi$ ) at  $\sim 2306$  nm. The input-output dependences were linear. For 1.3% OC, the laser generated a maximum peak output power of 2.4 W (average power: 0.12 W) with  $\eta = 11.5\%$ . The laser threshold was at  $P_{\text{inc}} = 2.0$  W and  $\eta_{\text{opt}}$  amounted to 10.3%. For higher output coupling, the laser performance deteriorated. The input-output dependences were linear up to at least  $P_{\text{inc}} = 23.2$  W.

The pump absorption  $\eta_{\text{abs,L}}$  was weakly dependent on the OC and the pump power and amounted to 60%. Thus, the maximum slope efficiency vs. the absorbed pump power was 19.2% (for  $T_{\text{OC}} = 1.3\%$ ) which is much lower than in the case of Ti:Sapphire pumping.

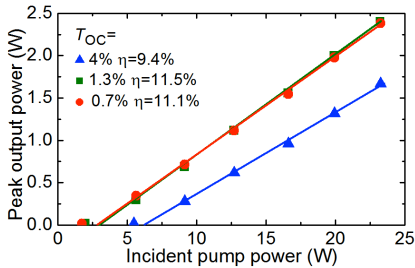


Fig. 8. Input-output dependences of diode-pumped  $\sim 2.3$   $\mu\text{m}$  Tm:LiYF<sub>4</sub> bulk laser,  $\eta$  – slope efficiency. The laser polarization is  $\pi$ . The pumping is quasi-CW (duty cycle: 1:20).

### D. Modeling of the laser performance

For modeling of the laser performance, we will consider the results achieved under Ti:Sapphire pumping. The model will account for ground-state bleaching, CR and ETU. The system of rate equations for Tm<sup>3+</sup> ions is as following:

$$\frac{dN_2}{dt} = 2K_{\text{CR}}N_1N_3 - 2K_{\text{ETU}}N_2^2 - \frac{N_2}{\tau_2} + \sigma_{\text{SE}}^{L2}I_{L2}N_3, \quad (7a)$$

$$\frac{dN_3}{dt} = \sigma_{\text{abs}}^P I_P N_1 - K_{\text{CR}}N_1N_3 + K_{\text{ETU}}N_2^2 - \frac{N_3}{\tau_{30}} - \sigma_{\text{SE}}^{L2}I_{L2}N_3, \quad (7b)$$

where,  $N_i$  ( $i = 1, 2, 3$ ) is the ion density for the  $i$ -th level, Fig. 1(b),  $N_1 + N_2 + N_3 = N_{\text{Tm}}$ ,  $t$  is time,  $K_{\text{CR}} = W_{\text{CR}}/N_{\text{Tm}}$  is the CR macroscopic parameter expressed in  $\text{cm}^3\text{s}^{-1}$ ,  $\tau_2$  is the lifetime of the 2<sup>nd</sup> level ( $^3\text{F}_4$ ),  $\tau_{30}$  is the intrinsic (unquenched) lifetime of the 3<sup>rd</sup> level ( $^3\text{H}_4$ ),  $\sigma_{\text{SE}}^{L2}$  is the SE cross-section at the laser frequency  $\nu_{L2}$  ( $^3\text{H}_4 \rightarrow ^3\text{H}_5$ )  $\sigma_{\text{abs}}^P$  is the absorption cross-section at the pump frequency  $\nu_P$ ,  $I_P$  and  $I_{L2}$  are the pump and laser intensities expressed in photons/(s·cm<sup>2</sup>). We will neglect the radiative decay in the  $3 \rightarrow 2$  channel because the

corresponding luminescence branching ratio  $\beta_{32}$  is small [38]. In Eq. (7), we assume no lasing at the  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transition with a frequency  $\nu_{L1}$  (so that  $I_{L1} \equiv 0$ ).

In the *first* approach, we will derive the pump quantum efficiency for the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition  $\eta_{q2}$  from the measured output power of the laser  $P_{\text{out}}$ . According to the definition of  $\eta_{q2}$  (the ratio of the number of emitted photons at  $\sim 2.3$   $\mu\text{m}$  to the number of absorbed pump photons), from the formalism of the rate equations, we have:

$$\eta_{q2} = \frac{\frac{N_3}{\tau_{30}} + \sigma_{\text{SE}}^{L2}I_{L2}N_3}{\sigma_{\text{abs}}^P I_P N_1}. \quad (8)$$

The population of the upper laser level  $N_3$  can be estimated from the threshold condition (gain is equal to losses):

$$\sigma_{\text{SE}}^{L2}N_3\ell = \frac{T_{\text{OC}} + L}{2}. \quad (9)$$

Here,  $\ell$  is the thickness of the crystal and  $L$  are the passive losses. In this equation, we neglect the axial dependence of the population  $N_3$ . By deriving  $N_3$  from Eq. (9) and substituting it into Eq. (8), we determined  $I_{L2}$  and, then, the output laser intensity  $I_{\text{out}} = T_{\text{OC}} \cdot (I_{L2}/2)$ . The output power  $P_{\text{out}}$  is then given by:

$$P_{\text{out}} = h\nu_{L2}\pi w_L^2 I_{\text{out}}, \quad (10a)$$

$$P_{\text{out}} = \frac{h\nu_{L2}}{h\nu_P} \frac{w_L^2}{w_P^2} \frac{T_{\text{OC}}}{T_{\text{OC}} + L} \eta_{q2} \eta_{\text{abs}} P_{\text{inc}} - \frac{T_{\text{OC}} h\nu_{L2} \pi w_L^2}{2\sigma_{\text{SE}}^{L2} \tau_{30}}. \quad (10b)$$

Here,  $w_L$  is the radius of the laser mode in the crystal and we have also taken into account that the pump absorption  $\eta_{\text{abs}} = \sigma_{\text{abs}}^P N_1 \ell$  and the incident pump power  $P_{\text{inc}} = h\nu_P \pi w_P^2 I_P$ . The first term of Eq. (10b) represents an expression for the laser slope efficiency vs. the absorbed pump power  $P_{\text{abs}} = \eta_{\text{abs}} P_{\text{inc}}$  containing four factors: the Stokes efficiency  $\eta_{\text{St}} = h\nu_{L2}/h\nu_P$ , the mode overlap efficiency  $\eta_{\text{mode}} = w_L^2/w_P^2$  (we assume  $\eta_{\text{mode}} \approx 1$ ), the output-coupling efficiency  $\eta_{\text{OC}} = T_{\text{OC}}/(T_{\text{OC}} + L)$  and the pump quantum efficiency  $\eta_{q2}$ . From Eq. (10b), the laser threshold is:

$$P_{\text{th}} = h\nu_P \pi w_P^2 \frac{T_{\text{OC}} + L}{2\sigma_{\text{SE}}^{L2} \tau_{30} \eta_{q2} \eta_{\text{abs}}}. \quad (11)$$

Using Eq. (10b), we were able to determine  $\eta_{q2}$  for each point at the input-output laser dependence from Fig. 6(a).

The calculated  $\eta_{q2}$  values are shown in Fig. 9. For all studied OCs, the quantum efficiency gradually increases with the incident pump power. The variation is from 0.14 to 1.27 for the optimum 1.3% OC. The values of  $\eta_{q2}$  exceeding unity represent a direct evidence of the effect of ETU on the laser performance. Indeed, ETU is responsible for re-feeding the upper laser level ( $^3\text{H}_4$ ) at the expense of the  $^3\text{F}_4$  population. The fact that  $\eta_{q2}$  is well below unity close to the laser

threshold clearly represents the effect of CR which is a detrimental process decreasing the upper laser level population.

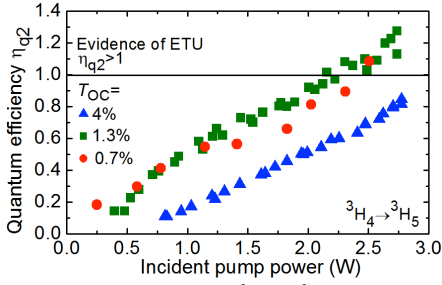


Fig. 9. Pump quantum efficiency for the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  laser channel (pumping to the  ${}^3\text{H}_4$  state)  $\eta_{q2}$  calculated using Eq. (10b).

To reveal the effect of CR and ETU on the pump quantum efficiency, we have derived another expression for  $\eta_{q2}$  based on the populations of the  $\text{Tm}^{3+}$  multiplets. In the steady-state conditions ( $dN_i/dt = 0$ ), by combining Eq. (8) and Eq. (7b), we obtained:

$$\eta_{q2} = 1 - \frac{K_{\text{CR}} N_1 N_3}{\sigma_{\text{abs}}^{\text{p}} I_{\text{p}} N_1} + \frac{K_{\text{ETU}} N_2^2}{\sigma_{\text{abs}}^{\text{p}} I_{\text{p}} N_1}. \quad (12)$$

This equation shows that that there exist two competitive energy-transfer processes which determine  $\eta_{q2}$ , namely CR and ETU. If both processes are negligible (an ideal case of almost zero doping concentration),  $\eta_{q2} \equiv 1$  and the laser slope efficiency will be limited by the Stokes efficiency. If there is no ETU, the quantum efficiency will be less than unity due to CR. Finally, if there are two processes (CR and ETU),  $\eta_{q2}$  may exceed unity as observed in Fig. 9.

There exist upper limit for  $\eta_{q2}$ . By combining Eq. (12), the rate-equation, Eq. 7(a), at the steady-state ( $dN_2/dt = 0$ ), and the intuitive expression for  $\eta_{q2}$ , Eq. (8), we obtain:

$$\eta_{q2} = 2 - \frac{1}{\sigma_{\text{abs}}^{\text{p}} I_{\text{p}} N_1} \left( \frac{N_3}{\tau_{30}} + \frac{N_2}{\tau_2} \right). \quad (13)$$

From this equation,  $\eta_{q2} \leq 2$ . The upper limit can be reached for a material exhibiting strong ETU and long lifetimes of the  ${}^3\text{H}_4$  and  ${}^3\text{F}_4$  multiplets and pumped well above the laser threshold when the laser operates solely at the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition, so that the  ${}^3\text{H}_4$  level is depopulated by  $\sim 2.3 \mu\text{m}$  laser emission and the  ${}^3\text{F}_4$  one is depopulated by ETU.

From these considerations, it is possible to explain the decrease of pump absorption  $\eta_{\text{abs}}$  (bleaching) with the pump power, Fig. 7. This is because when there is no laser operation at the  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transition, the population of the ground-state  ${}^3\text{H}_6$  is not clamped by the threshold condition. Thus, with an increased pump power, the ground-state is depopulated while the  $\text{Tm}^{3+}$  ions are accumulated in the metastable intermediate  ${}^3\text{F}_4$  state. Note that when the laser operates at both the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  and  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transitions simultaneously,  $\eta_{\text{abs}}$  is expected to be nearly constant with the pump power.

Within the *second* approach, we solved the system of rate equations, Eq. (7), numerically accounting for the spatial and axial distribution of the pump and laser fields in the crystal. Then, the laser output power at  $\sim 2.3 \mu\text{m}$  was determined from Eq. (10a) and  $\eta_{q2}$  was determined from Eq. (12).

First, we performed the calculations assuming that the laser operates solely at the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition ( $I_{\text{L}1} \equiv 0$ ). Three different  $\text{Tm}^{3+}$  doping levels of 1.5, 3.5 and 6.5 at.% were considered. The CR and ETU parameters were as following:  $K_{\text{CR}} = 0.52, 1.21$  and  $2.24 \times 10^{-17} \text{ cm}^3 \text{ s}^{-1}$  and  $K_{\text{ETU}} = 0.3, 1.4$  and  $4.5 \times 10^{-19} \text{ cm}^3 \text{ s}^{-1}$ , respectively. The calculations were done under two assumptions: (i) there exist both CR and ETU processes ( $K_{\text{CR}} \neq 0, K_{\text{ETU}} \neq 0$ ); (ii) there exist only CR while ETU is absent ( $K_{\text{CR}} \neq 0, K_{\text{ETU}} = 0$ ). The spectroscopic parameters of  $\text{Tm}^{3+}$  ions were as following:  $\sigma_{\text{SE}}^{L2} = 0.57 \times 10^{-20} \text{ cm}^2$ ,  $\sigma_{\text{abs}}^{\text{p}} = 0.63 \times 10^{-20} \text{ cm}^2$  at 791 nm (for  $\pi$ -polarization) [46],  $\tau_{30} = 2.3 \text{ ms}$ ,  $\tau_2 = 10 \text{ ms}$  [46]. The incident pump power was fixed ( $P_{\text{inc}} = 3.0 \text{ W}$ ).

The results on the output power at  $\sim 2.3 \mu\text{m}$  are presented in Fig. 10(a). When there is no ETU in the system ( $K_{\text{CR}} \neq 0, K_{\text{ETU}} = 0$ ), for a fixed (small) radius of the laser mode (e.g.,  $w_{\text{L}} = 60 \mu\text{m}$  as in our case), the output power slightly increases with the  $\text{Tm}^{3+}$  doping due to the increased pump absorption. When the ETU is present ( $K_{\text{CR}} \neq 0, K_{\text{ETU}} \neq 0$ ), the output power is greatly increased and this effect becomes more evident for higher  $\text{Tm}^{3+}$  doping levels because the action of ETU against CR is enhanced. Moreover, for each  $\text{Tm}^{3+}$  concentration, there is an optimum radius of the laser mode maximizing the output power. With an increase of the  $\text{Tm}^{3+}$  doping, the optimum  $w_{\text{L}}$  value decreases. For 3.5 at.% Tm-doping, the laser geometry used in the present work, cf. Fig. 5, provided almost optimum  $w_{\text{L}}$  value.

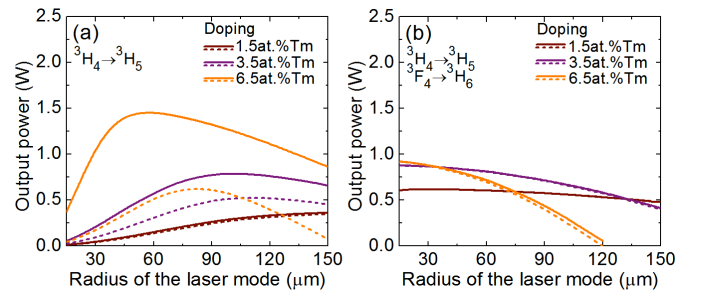


Fig. 10. Calculated output power at  $\sim 2.3 \mu\text{m}$  of a diode-pumped  $\text{Tm}:\text{LiYF}_4$  laser with different doping levels, *solid curves* -  $K_{\text{CR}} \neq 0, K_{\text{ETU}} \neq 0$ , *dashed ones* -  $K_{\text{CR}} \neq 0, K_{\text{ETU}} = 0$ : (a) the laser operating at the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition only; (b) the laser operating at both the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  and  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transitions simultaneously. The  $\text{Tm}^{3+}$  doping is 1.5, 3.5 and 6.5 at.%,  $P_{\text{inc}} = 3.0 \text{ W}$ ,  $T_{\text{OC}} = 2.0\%$ ,  $L = 0.2\%$ ,  $\ell = 9.0 \text{ mm}$ .

Furthermore, we have analyzed the laser performance for operation at both the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  and  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transitions simultaneously. For this, the term  $-\sigma_{\text{SE}}^{L1} I_{\text{L}1} N_2$  representing stimulated-emission at  $\nu_{\text{L}1}$  (at  $\sim 1.9 \mu\text{m}$ ) was added to the rate-equation, Eq. (7a). The results are shown in Fig. 10(b). In this case, the effect of ETU on the laser performance is minor because population of the  ${}^3\text{F}_4$  state is clamped by the threshold condition for the  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  laser. For a fixed (small)  $w_{\text{L}}$ , the output power only slightly increases with  $\text{Tm}^{3+}$  doping due to



the increased pump absorption and finally saturates.

To conclude, the simultaneous operation of the Tm lasers at both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transitions is mostly detrimental for their  $\sim 2.3 \mu\text{m}$  laser performance, especially at high doping levels. Moreover, in the case of single laser operation ( $^3\text{H}_4 \rightarrow ^3\text{H}_5$ ) the efficiency of the  $\sim 2.3 \mu\text{m}$  laser can be greatly enhanced by using highly  $\text{Tm}^{3+}$ -doped crystals due to the ETU effect.

The existence of the optimum size of the laser mode for the  $\sim 2.3 \mu\text{m}$  Tm:LiYF<sub>4</sub> laser operating solely at the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition is due to (i) strong dependence of pump absorption  $\eta_{\text{abs}}$  or, equivalently, ground-state bleaching, on the pump spot radius  $w_p$  (notice that in this modeling, we assumed  $w_L \approx w_p$ ), see Fig. 11(a), and (ii) increase of the laser threshold with increasing pump spot size. Physically, the first effect is explained as following: if there is no laser operation at the  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transition, the population of the ground-state ( $^3\text{H}_6$ ) is not clamped by the threshold condition and thus it can be depopulated for high pump intensities (for small  $w_p$ ). ETU increases the pump absorption because it brings excited  $\text{Tm}^{3+}$  ions back to the ground-state. Thus, the optimum size of the laser mode decreases with  $\text{Tm}^{3+}$  doping due to enhanced ETU.

When the laser operates at both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transitions simultaneously, the size of the pump mode and ETU have minor action on the pump absorption, Fig. 11(b).

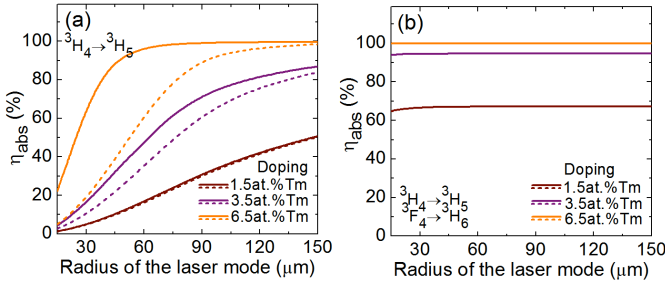


Fig. 11. Calculated pump absorption  $\eta_{\text{abs}}$  for a diode-pumped Tm:LiYF<sub>4</sub> laser with different doping levels, *solid curves* –  $K_{\text{CR}} \neq 0$ ,  $K_{\text{ETU}} \neq 0$ , *dashed ones* –  $K_{\text{CR}} \neq 0$ ,  $K_{\text{ETU}} = 0$ : (a) the laser operating at the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition only; (b) the laser operating at both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transitions simultaneously. The parameters used for modeling are listed in the text.

In Fig. 12, the calculated pump quantum efficiency  $\eta_{q2}$  for the Tm:LiYF<sub>4</sub> laser is shown. When the laser operates solely at the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition and there is no ETU in the system ( $K_{\text{CR}} \neq 0$ ,  $K_{\text{ETU}} = 0$ ), the  $\eta_{q2}$  value has an upper limit of 1 and it has almost no dependence on the  $\text{Tm}^{3+}$  doping level for small radii of the pump mode. If the ETU is present ( $K_{\text{CR}} \neq 0$ ,  $K_{\text{ETU}} \neq 0$ ), the pump quantum efficiency greatly increases with  $\text{Tm}^{3+}$  doping approaching the upper limit of 2, Fig. 12(a). Note that for about 1–2 at.% Tm-doping which was typically used in the previous studies [17,19,20,25],  $\eta_{q2}$  is below 1 which agrees with the observed laser slope efficiencies. For 3.5 at.% Tm-doping, as in our case,  $\eta_{q2} > 1$  can be observed, cf. Fig. 9.

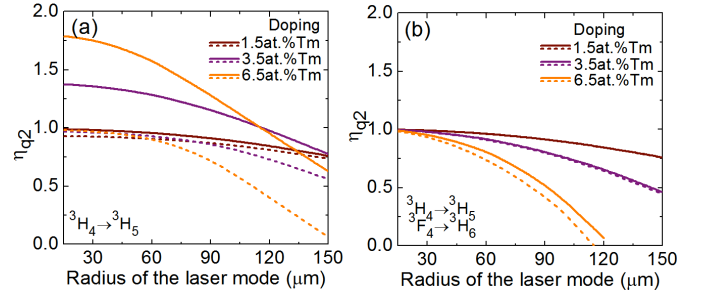


Fig. 12. Calculated pump quantum efficiency  $\eta_{q2}$  for a diode-pumped Tm:LiYF<sub>4</sub> laser with different doping levels, *solid curves* –  $K_{\text{CR}} \neq 0$ ,  $K_{\text{ETU}} \neq 0$ , *dashed ones* –  $K_{\text{CR}} \neq 0$ ,  $K_{\text{ETU}} = 0$ : (a) the laser operating at the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition only; (b) the laser operating at both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transitions simultaneously. The parameters used for modeling are listed in the text.

When the laser operates at both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transitions simultaneously,  $\eta_{q2}$  cannot exceed unity even under the conditions of high  $\text{Tm}^{3+}$  doping and, consequently, strong ETU, Fig. 12(b).

Using the above described second approach, we calculated the values of the maximum output power  $P_{\text{out}}$ , threshold power  $P_{\text{th}}$ , slope efficiency  $\eta$  (vs. the incident pump power) and the maximum pump quantum efficiency  $\eta_{q2(\text{max})}$  for the studied 3.5 at.% Tm:LiYF<sub>4</sub> laser, see Table III. The results of calculation are in reasonable agreement with the experimental data.

This confirms the first observation of more than unity pump quantum efficiency  $\eta_{q2}$  for the  $\sim 2.3 \mu\text{m}$  laser transition in bulk Tm:LiYF<sub>4</sub>.

$T_{\text{OC}}$	Data	$P_{\text{out}}$ , W	$P_{\text{th}}$ , W	$\eta$ , %	$\eta_{q2(\text{max})}$
0.7%	Exp.	0.49	0.24	30.3	<b>1.08</b>
	Calc.	0.52	0.24	20.8	<b>1.30</b>
1.3%	Exp.	0.73	0.40	34.6	<b>1.27</b>
	Calc.	0.65	0.36	27.2	<b>1.23</b>
4%	Exp.	0.55	0.81	35.9	<b>0.85</b>
	Calc.	0.63	0.99	36.3	<b>0.93</b>

\* $P_{\text{out}}$  – output power,  $P_{\text{th}}$  – threshold incident power,  $\eta$  – slope efficiency vs. the incident pump power,  $\eta_{q2(\text{max})}$  – pump quantum efficiency at the maximum pump power.

#### IV. WAVEGUIDE LASERS AT $\sim 2.3 \mu\text{m}$

##### A. Fabrication of waveguides

Single-crystalline 6.2 at.% Tm, 3.5 at.% Gd:LiYF<sub>4</sub> thin film was grown on undoped (001)-oriented LiYF<sub>4</sub> substrate by the Liquid Phase Epitaxy (LPE) method [54]. The actual  $\text{Tm}^{3+}$  ion density  $N_{\text{Tm}} = 8.56 \times 10^{20} \text{ cm}^{-3}$ . The optically passive Gd<sup>3+</sup> ions were added to enhance the refractive index contrast between the active layer and the substrate ( $\Delta n = 2.3 \pm 0.5 \times 10^{-3}$ ). The film thickness was  $30 \mu\text{m}$ .

The films were further microstructured by diamond saw dicing resulting in surface channel (ridge) waveguides (WGs) oriented along the *a*-axis and having a square cross-section of  $30 \times 30 \mu\text{m}^2$ . The length of the WGs was 8.0 mm. The WG propagation losses were  $0.28 \pm 0.1 \text{ dB/cm}$  at  $\sim 1.9 \mu\text{m}$ . More details can be found in [54].

### B. Laser set-up

The scheme of the waveguide laser is shown in Fig. 11. The sample with the WG was mounted on a Cu-holder using a silver thermal paste. It was passively cooled. The laser cavity was composed of a flat PM coated for HR at 1.88-2.32  $\mu\text{m}$  and HT at the pump wavelength ( $T = 69\%$  at 0.79  $\mu\text{m}$ ), and a set of two flat OCs coated for HT at 1.83-1.88  $\mu\text{m}$  ( $T = 90\% / 97\%$ ) and having a transmission of 4% / 1.3% at 2.3  $\mu\text{m}$ , respectively. Both PM and OC were placed as close as possible to the WG end-facets. No index-matching liquid was used to avoid damage of the optical elements.

As a pump source, we used the same Ti:Sapphire laser, see Section IIIA. The pump polarization corresponded to  $\pi$  in the WG. The pump beam was focused by an uncoated  $\text{CaF}_2$  spherical lens ( $f = 40$  mm,  $T = 93.8\%$  at 0.79  $\mu\text{m}$ ) providing a pump spot diameter at the input face of the WG  $2w_p$  of  $\sim 30$   $\mu\text{m}$ . The pump coupling efficiency  $\eta_{\text{coupl}}$  was determined from pump-transmission measurements at 0.84  $\mu\text{m}$  (out of  $\text{Tm}^{3+}$  absorption) to be  $87 \pm 1\%$ . The pump absorption at the laser threshold  $\eta_{\text{abs}(1\text{-pass})}$  was measured to be  $71.0 \pm 0.5\%$ . Both OCs provided partial reflection at the pump wavelength ( $R = 93\% / 96\%$ , respectively) and thus the WG was pumped in a double-pass. The calculated total pump absorption  $\eta_{\text{abs}(2\text{-pass})}$  amounted to 90.1%. The pump beam was mechanically modulated using a mechanical chopper (1:2 duty cycle, 10 ms pump pulses).

The WG laser operated at the fundamental transverse mode. The mode radius  $w_L$  was 15  $\mu\text{m}$ .

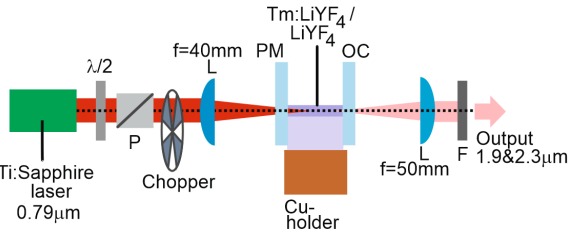


Fig. 13. Scheme of the  $\sim 2.3$   $\mu\text{m}$  Tm:LiYF<sub>4</sub> channel WG laser:  $\lambda/2$  – rotatory half-wave plate, P – Glan-Taylor polarizer, L – lens, PM – pump mirror, OC – output coupler, F – cut-off / bandpass filter.

The output laser beam was collimated using a spherical lens ( $f = 50$  mm). The total output power was determined after filtering the residual pump using a cut-off filter (FEL 900, Thorlabs). The power at  $\sim 2.3$   $\mu\text{m}$  was separately determined using a bandpass filter (FB2250-500, Thorlabs).

### C. Laser performance

The WG Tm:LiYF<sub>4</sub> laser operated at both  $\sim 1.9$   $\mu\text{m}$  and  $\sim 2.3$   $\mu\text{m}$  transitions for both OCs. The laser output was linearly polarized ( $\pi$ ).

The best results were achieved using the output coupler having a transmission of 90% / 4% at  $\sim 1.9$   $\mu\text{m}$  / 2.3  $\mu\text{m}$ . The maximum peak total output power reached 1.13 W with a total slope efficiency  $\eta^\Sigma$  of 64.2% (vs. the coupled pump power). The laser threshold was at 0.10 W and the total optical-to-optical efficiency  $\eta^\Sigma_{\text{opt}}$  amounted to 59.4%. Near the threshold, the laser operated solely at the  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transition. For the pump power exceeding 0.68 W, the emission due to the  $^3\text{H}_4 \rightarrow$

$^3\text{H}_5$  transition appeared, as shown in Fig. 11(a). The corresponding peak output power reached 0.23 W with  $\eta = 17.8\%$ . According to the pump absorption efficiency  $\eta_{\text{abs}(2\text{-pass})}$ , the slope efficiency vs. the absorbed pump power was 19.8% being smaller than in the bulk laser. For the second studied OC, the laser performance was inferior.

The typical spectra of the laser emission are shown in Fig. 11(b). The emission corresponding to the  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transition occurred at 1877-1881 nm in agreement with the gain spectra for  $\pi$ -polarization. The  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  laser transition operated at 2304-2307 nm (both for  $T_{\text{OC}} = 90\% / 4\%$ ). The multi-peak spectral behavior for both transitions is due to the etalon effects at the WG / mirror interfaces.

The achieved results represent the first  $\sim 2.3$   $\mu\text{m}$  thulium waveguide laser.

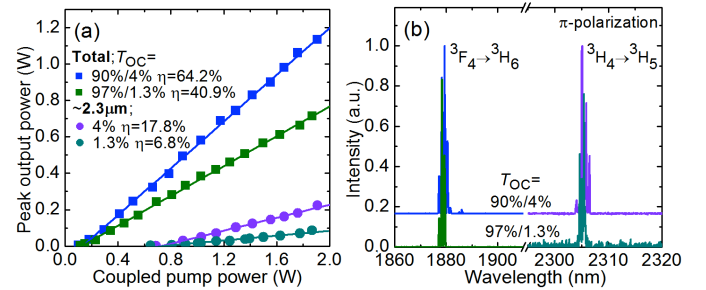


Fig. 14. Ti:Sapphire pumped  $\sim 1.9$   $\mu\text{m}$  & 2.3  $\mu\text{m}$  Tm:LiYF<sub>4</sub> waveguide laser: (a) input-output dependences,  $\eta$  – slope efficiency; (b) typical laser emission spectra. The laser polarization is  $\pi$ . The pumping is quasi-CW (duty cycle: 1:2).

### D. Modeling of laser performance

The performance of the WG laser was modeled numerically using the second approach described above. The results of this modeling are summarized in Table IV. Here,  $P_{\text{out}}^\Sigma$  is the total output power (for both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  laser transitions),  $P_{\text{th}}^\Sigma$  is the corresponding laser threshold and  $\eta^\Sigma$  is the corresponding slope efficiency (both vs. the coupled pump power). The values without the “ $\Sigma$ ” superscript refer solely to the  $\sim 2.3$   $\mu\text{m}$  emission. For the WG laser, it was not possible to derive the  $\eta_{q2}$  value from the output power (using the first approach) because of simultaneous operation of the laser at  $\sim 1.9$   $\mu\text{m}$  and  $\sim 2.3$   $\mu\text{m}$ .

TABLE IV  
LASER PERFORMANCE\* OF  $\sim 2.3$   $\mu\text{m}$  WAVEGUIDE Tm:LiYF<sub>4</sub> LASERS

$T_{\text{OC}}$	Data	$P_{\text{out}}^\Sigma$ W	$P_{\text{th}}^\Sigma$ W	$\eta^\Sigma$ %	$P_{\text{out}}$ W	$P_{\text{th}}$ W	$\eta$ , %	$\eta_{q2(\text{max})}$
90% / 4%	Exp.	1.13	0.10	64.2	0.23	0.68	17.8	–
	Calc.	0.99	<0.1	37.4	0.23	<0.2	12.0	<b>0.91</b>
97% / 1.3%	Exp.	0.71	0.11	40.9	0.09	0.64	6.8	–
	Calc.	0.84	<0.1	37.1	0.10	<0.2	5.1	<b>0.93</b>

\* $P_{\text{out}}$  – output power,  $P_{\text{th}}$  – threshold incident power,  $\eta$  – slope efficiency vs. the incident pump power (the values with “ $\Sigma$ ”: emission at both the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_4 \rightarrow ^3\text{H}_6$  transitions, without “ $\Sigma$ ”: emission at the  $^3\text{H}_4 \rightarrow ^3\text{H}_5$  transition,  $\eta_{q2(\text{max})}$  – pump quantum efficiency at the maximum pump power.

The model reasonably explains the observed output power at  $\sim 2.3$   $\mu\text{m}$  while it predicts lower values for the laser threshold. The maximum  $\eta_{q2}$  values are still below 1 in agreement with the prediction for simultaneous operation at

the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  and  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transitions, Fig. 12(b).

## V. CONCLUSIONS

To conclude, the laser operation at the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$   $\text{Tm}^{3+}$  transition is a promising route towards efficient mid-IR bulk and waveguide oscillators operating around  $\sim 2.3$   $\mu\text{m}$ . Under the condition that the competitive  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  laser channel is suppressed, a pump quantum efficiency of more than unity (potentially, up to 2) can be achieved thus leading to a laser slope efficiency well exceeding the Stokes limit. This is due to the energy-transfer upconversion acting against cross-relaxation and populating the upper laser level. Strong ETU is linked to the use of moderate and high  $\text{Tm}^{3+}$  doping levels that simultaneously bring high pump absorption efficiency and, in part, to the adjusted pump mode size.

Fluoride  $\text{LiYF}_4$  crystals with moderate  $\text{Tm}^{3+}$  doping levels of few at.% appear as excellent candidates for highly-efficient  $\sim 2.3$   $\mu\text{m}$  lasers because of a combination of easy  $\text{Tm}^{3+}$  doping, low phonon energies and good thermo-mechanical properties of the host crystal and suitable spectroscopic behavior of the dopant  $\text{Tm}^{3+}$  ions. In the present work, we report on a compact bulk 3.5 at.%  $\text{Tm}:\text{LiYF}_4$  laser generating a maximum output power of 0.72 W (quasi-CW operation) at 2306  $\mu\text{m}$  with a record-high slope efficiency of 47.3% versus the absorbed pump power (thus overcoming the Stokes efficiency, 34.4%). We show the first experimental evidence of more than unity pump quantum efficiency in this laser. By applying diode pumping, the power scaling strategy is demonstrated with a clear potential for improvement.

We also report on the first  $\sim 2.3$   $\mu\text{m}$   $\text{Tm}$  waveguide laser based on epitaxially-grown 6.2 at.%  $\text{Tm}:\text{LiYF}_4$  layers. Due to the simultaneous operation of the waveguide laser at both the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  and  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transitions, the pump quantum efficiency was upper-limited to be less than unity despite the high  $\text{Tm}^{3+}$  doping level. The laser generated 0.23 W at 2304–2307 nm with a slope efficiency of 19.8% versus the absorbed pump power. Further efforts on  $\sim 2.3$   $\mu\text{m}$   $\text{Tm}$  waveguide lasers should be focused on suppression of laser operation at the high-gain  ${}^3\text{F}_4 \rightarrow {}^3\text{H}_6$  transition, e.g., by dielectric coatings.

Our conclusions about the mechanism of  $\sim 2.3$   $\mu\text{m}$  laser operation are valid for other  $\text{Tm}^{3+}$ -doped fluoride crystals, such as  $\text{CaF}_2$ ,  $\text{LiLuF}_4$ ,  $\text{BaY}_2\text{F}_8$ , or even other oxide hosts. A comparative study of CR and ETU parameters of these materials is required to select the best fluoride gain material for the laser operation at the  ${}^3\text{H}_4 \rightarrow {}^3\text{H}_5$  transition.

## REFERENCES

- [1] F. J. McAleavey, J. O'Gorman, J. F. Donegan, B. D. MacCraith, J. Hegarty, and G. Mazé, "Narrow linewidth, tunable  $\text{Tm}^{3+}$ -doped fluoride fiber laser for optical-based hydrocarbon gas sensing," *IEEE J. Sel. Top. Quantum Electron.*, vol. 3, No. 4, pp. 1103–1111, Aug. 1997.
- [2] M. E. Webber, J. Wang, S. T. Sanders, D. S. Baer, and R. K. Hanson, "In situ combustion measurements of  $\text{CO}$ ,  $\text{CO}_2$ ,  $\text{H}_2\text{O}$  and temperature using diode laser absorption sensors," *Proc. Combust. Inst.*, vol. 28, no. 1, pp. 407–413, 2000.
- [3] F. J. McAleavey, J. O'Gorman, J. F. Donegan, J. Hegarty, and G. Maze, "Extremely high sensitivity gas detection at 2.3  $\mu\text{m}$  using a grazing incidence  $\text{Tm}^{3+}$  fibre laser cavity," *Sens. Actuator A – Phys.*, vol. 87, no. 3, pp. 107–112, Jan. 2001.
- [4] J. Cihelka, I. Matulková, and S. Civiš, "Laser diode photoacoustic and FTIR laser spectroscopy of formaldehyde in the 2.3  $\mu\text{m}$  and 3.5  $\mu\text{m}$  spectral range," *J. Molec. Spectr.*, vol. 256, no. 1, pp. 68–74, July 2009.
- [5] A. Garnache, A. Liu, L. Cerutti, and A. Campargue, "Intracavity laser absorption spectroscopy with a vertical external cavity surface emitting laser at 2.3  $\mu\text{m}$ : Application to water and carbon dioxide," *Chem. Phys. Lett.*, vol. 416, no. 1–3, pp. 22–27, Nov. 2005.
- [6] S. T. Fard, W. Hofmann, P. T. Fard, G. Bohm, M. Ortsiefer, E. Kwok, M. C. Amann, and L. Chrostowski, "Optical absorption glucose measurements using 2.3  $\mu\text{m}$  vertical-cavity semiconductor lasers," *IEEE Photon. Technol. Lett.*, vol. 20, no. 11, pp. 930–932, June 2008.
- [7] I. T. Sorokina, E. Sorokin, S. Mirov, V. Fedorov, V. Badikov, V. Panyutin, and K. I. Schaffers, "Broadly tunable compact continuous-wave  $\text{Cr}^{2+}:\text{ZnS}$  laser," *Opt. Lett.*, vol. 27, no. 12, pp. 1040–1042, June 2002.
- [8] G. J. Wagner, T. J. Carrig, R. H. Page, K. I. Schaffers, J.-O. Ndad, X. Ma, and A. Burger, "Continuous-wave broadly tunable  $\text{Cr}^{2+}:\text{ZnSe}$  laser," *Opt. Lett.*, vol. 24, no. 1, pp. 19–21, Jan. 1999.
- [9] L. Cerutti, A. Garnache, A. Ouvrard, M. Garcia, and F. Genty, "Vertical cavity surface emitting laser sources for gas detection," *Phys. Status Solidi A*, vol. 202, no. 4, pp. 631–635, Feb. 2005.
- [10] E. Geerlings, M. Rattunde, J. Schmitz, G. Kaufel, H. Zappe, and J. Wagner, "Widely tunable GaSb-based external cavity diode laser emitting around 2.3  $\mu\text{m}$ ," *IEEE Photon. Technol. Lett.*, vol. 18, no. 18, pp. 1913–1915, Sept. 2006.
- [11] R. Wang, S. Sprengel, A. Malik, A. Vasiliev, G. Boehm, R. Baets, M. C. Amann, and G. Roelkens, "Heterogeneously integrated III–V-on-silicon 2.3  $\mu\text{m}$  distributed feedback lasers based on a type-II active region," *Appl. Phys. Lett.*, vol. 109, no. 22, pp. 221111, Nov. 2016.
- [12] G. Boehm, A. Bachmann, J. Rosskopf, M. Ortsiefer, J. Chen, A. Hangauer, R. Meyer, R. Strzoda, and M. C. Amann, "Comparison of InP- and GaSb-based VCSELs emitting at 2.3  $\mu\text{m}$  suitable for carbon monoxide detection," *J. Cryst. Growth*, vol. 323, no. 1, pp. 442–445, May 2011.
- [13] R. C. Stoneman, and L. Esterowitz, "Efficient, broadly tunable, laser-pumped  $\text{Tm}:\text{YAG}$  and  $\text{Tm}:\text{YSGG}$  cw lasers," *Opt. Lett.*, vol. 15, no. 9, pp. 486–488, May 1990.
- [14] K. van Dalen, S. Aravazhi, C. Grivas, S. M. Garcia-Blanco, and M. Pollnau, "Thulium channel waveguide laser with 1.6 W of output power and  $\sim 80\%$  slope efficiency," *Opt. Lett.*, vol. 39, no. 15, pp. 4380–4383, Aug. 2014.
- [15] H. P. Jenssen, A. Linz, R. P. Leavitt, C. A. Morrison, and D. E. Wortman, "Analysis of the optical spectrum of  $\text{Tm}^{3+}$  in  $\text{LiYF}_4$ ," *Phys. Rev. B*, vol. 11, no. 1, pp. 92–101, Jan. 1975.
- [16] J. Caird, L. DeShazer, and J. Nella, "Characteristics of room-temperature 2.3- $\mu\text{m}$  laser emission from  $\text{Tm}^{3+}$  in  $\text{YAG}$  and  $\text{YAlO}_3$ ," *IEEE J. Quantum Electron.*, vol. 11, no. 11, pp. 874–881, Nov. 1975.
- [17] J. F. Pinto, L. Esterowitz, and G. H. Rosenblatt, " $\text{Tm}^{3+}:\text{YLF}$  laser continuously tunable between 2.20 and 2.46  $\mu\text{m}$ ," *Opt. Lett.*, vol. 19, no. 12, pp. 883–885, June 1994.
- [18] D. Bar-Joseph, "2.32-micron flash-lamp-pumped high-repetition-rate laser operation in  $\text{Tm}:\text{Cr}:\text{YAG}$ ," *Proc. SPIE*, vol. 1627, pp. 81–85, June 1992.
- [19] V. Sudesh, and J. A. Piper, "Spectroscopy, modeling, and laser operation of thulium-doped crystals at 2.3  $\mu\text{m}$ ," *IEEE J. Quantum Electron.*, vol. 36, no. 7, pp. 879–884, July 2000.
- [20] F. Canbaz, I. Yorulmaz, and A. Sennaroglu, "2.3- $\mu\text{m}$   $\text{Tm}^{3+}:\text{YLF}$  laser passively Q-switched with a  $\text{Cr}^{2+}:\text{ZnSe}$  saturable absorber," *Opt. Lett.*, vol. 42, no. 9, pp. 1656–1659, May 2017.
- [21] A. Braud, S. Girard, J. L. Doualan, M. Thuau, R. Moncorgé, and A. M. Tkachuk, "Energy-transfer processes in  $\text{Yb}:\text{Tm}$ -doped  $\text{KY}_3\text{F}_{10}$ ,  $\text{LiYF}_4$ , and  $\text{BaY}_2\text{F}_8$  single crystals for laser operation at 1.5 and 2.3  $\mu\text{m}$ ," *Phys. Rev. B*, vol. 61, no. 8, pp. 5280–5292, Feb. 2000.
- [22] A. Dening, P. A. Möbert, and G. Huber, "Diode-pumped continuous-wave, quasi-continuous-wave, and Q-switched laser operation of  $\text{Yb}^{3+}$ ,  $\text{Tm}^{3+}:\text{YLiF}_4$  at 1.5 and 2.3  $\mu\text{m}$ ," *J. Appl. Phys.*, vol. 84, no. 11, pp. 5900–5904, Nov. 1998.
- [23] P. S. F. De Matos, N. U. Wetter, L. Gomes, I. M. Ranieri, and S. L. Baldochi, "A high power 2.3  $\mu\text{m}$   $\text{Yb}:\text{Tm}:\text{YLF}$  laser diode-pumped simultaneously at 685 and 960 nm," *J. Opt. A*, vol. 10, no. 10, pp. 104009–1–7, Aug. 2008.
- [24] G. J. Kintz, L. Esterowitz, and R. Allen, "Cascade laser emission at 2.31 and 2.08  $\mu\text{m}$  from laser diode pumped  $\text{Tm}:\text{Ho}:\text{LiYF}_4$  at room temperature," in *Advanced Solid State Lasers*, 26 October 1987,

- Williamsburg, Virginia United States: OSA Technical Digest, 1987, vol. paper MC2.
- [25] I. Yorulmaz, and A. Sennaroglu, "Low-threshold diode-pumped 2.3- $\mu\text{m}$   $\text{Tm}^{3+}$ :YLF lasers," *IEEE J. Sel. Top. Quantum Electron.*, vol. 24, no. 5, pp. 1601007-1-7, Sept-Oct. 2018.
  - [26] F. Canbaz, I. Yorulmaz, and A. Sennaroglu, "Kerr-lens mode-locked 2.3- $\mu\text{m}$   $\text{Tm}^{3+}$ :YLF laser as a source of femtosecond pulses in the mid-infrared," *Opt. Lett.*, vol. 42, no. 19, pp. 3964-3967, Oct. 2017.
  - [27] R. Souillard, A. Tyazhev, J.L. Doualan, A. Braud, A. Hideur, M. Laroche, B. Xu, and P. Camy, "2.3  $\mu\text{m}$   $\text{Tm}^{3+}$ :YLF mode-locked laser," *Opt. Lett.*, vol. 42, no. 18, pp. 3534-3536, Sept. 2017.
  - [28] R. Allen, and L. Esterowitz, "CW diode pumped 2.3  $\mu\text{m}$  fiber laser," *Appl. Phys. Lett.*, vol. 55, no. 8, pp. 721-722, June 1989.
  - [29] J. N. Carter, D. C. Hanna, R. G. Smart, and A. C. Tropper, "Thulium-doped fluorozirconate fiber lasers operating at around 0.8, 1.47, 1.9, and 2.3  $\mu\text{m}$  pumped at 0.79  $\mu\text{m}$ ," in *Advanced Solid State Lasers, 18 March 1991, Hilton Head, South Carolina, United States: OSA Proceedings Series*, 1991, vol. 10, paper. MIL13.
  - [30] R.M. El-Agmy, and N.M. Al-Hosiny, "2.31  $\mu\text{m}$  laser under up-conversion pumping at 1.064  $\mu\text{m}$  in  $\text{Tm}^{3+}$ :ZBLAN fibre lasers," *Electron. Lett.*, vol. 46, no. 13, pp. 936-937, June 2010.
  - [31] S. V. Muravyev, E. A. Anashkina, A. V. Andrianov, V. V. Dorofeev, S. E. Motorin, M. Y. Koptev, and A. V. Kim, "Dual-band  $\text{Tm}^{3+}$ -doped tellurite fiber amplifier and laser at 1.9  $\mu\text{m}$  and 2.3  $\mu\text{m}$ ," *Sci. Rep.*, vol. 8, no. 1, pp. 16164, Nov. 2018.
  - [32] C. Jia, B.J. Shastri, P.R. Prucnal, M. Saad, and L. R. Chen, "Simultaneous Q-switching of a  $\text{Tm}^{3+}$ :ZBLAN fiber laser at 1.9  $\mu\text{m}$  and 2.3  $\mu\text{m}$  using graphene," *IEEE Photon. Technol. Lett.*, vol. 29, no. 4, pp. 405-408, Jan. 2017.
  - [33] M. Schellhorn, "High-power diode-pumped  $\text{Tm}$ :YLF laser," *Appl. Phys. B*, vol. 91, no. 1, pp. 71-74, Apr. 2008.
  - [34] P. Loiko, J. M. Serres, X. Mateos, S. Tacchini, M. Tonelli, S. Veronesi, D. Parisi, A. Di Lieto, K. Yumashev, U. Griebner, and V. Petrov, "Comparative spectroscopic and thermo-optic study of  $\text{Tm}:\text{LiLnF}_4$  ( $\text{Ln} = \text{Y}$ , Gd, and Lu) crystals for highly-efficient microchip lasers at  $\sim 2 \mu\text{m}$ ," *Opt. Mater. Express*, vol. 7, no. 3, pp. 844-854, Mar. 2017.
  - [35] S. A. Miller, H. E. Rast, and H. H. Caspers, "Lattice vibrations of  $\text{LiYF}_4$ ," *J. Chem. Phys.*, vol. 52, no. 8, pp. 4172-4175, Apr. 1970.
  - [36] R. L. Aggarwal, D. J. Ripin, J. R. Ochoa, and T. Y. Fan, "Measurement of thermo-optic properties of  $\text{Y}_3\text{Al}_5\text{O}_{12}$ ,  $\text{Lu}_3\text{Al}_5\text{O}_{12}$ ,  $\text{YAlO}_3$ ,  $\text{LiYF}_4$ ,  $\text{LiLuF}_4$ ,  $\text{BaY}_2\text{F}_8$ ,  $\text{KGd}(\text{WO}_4)_2$ , and  $\text{KY}(\text{WO}_4)_2$  laser crystals in the 80–300 K temperature range," *J. Appl. Phys.*, vol. 98, no. 10, pp. 103514-1-14, Nov. 2005.
  - [37] B. Cockayne, J. G. Plant, and R. A. Clay, "The Czochralski growth and laser characteristics of  $\text{Li}(\text{Y}, \text{Er}, \text{Tm}, \text{Ho})\text{F}_4$  and  $\text{Li}(\text{Lu}, \text{Er}, \text{Tm}, \text{Ho})\text{F}_4$  scheelite single crystals," *J. Cryst. Growth*, Vol. 54, No. 3, pp.407-413, Sept. 1981.
  - [38] B. M. Walsh, N. P. Barnes, and B. Di Bartolo, "Branching ratios, cross sections, and radiative lifetimes of rare earth ions in solids: Application to  $\text{Tm}^{3+}$  and  $\text{Ho}^{3+}$  ions in  $\text{LiYF}_4$ ," *J. Appl. Phys.*, vol. 3, no. 5, pp. 2772-2787, Mar. 1998.
  - [39] S. So, J. I. Mackenzie, D. P. Sheperd, W. A. Clarkson, J. G. Bettterton, and E. K. Gorton, "A power-scaling strategy for longitudinally diode-pumped  $\text{Tm}$ :YLF lasers," *Appl. Phys. B*, vol. 84, no. 3, pp. 389–393, Sept. 2006.
  - [40] B. Aull, and H. Jenssen, "Vibronic interactions in  $\text{Nd}:\text{YAG}$  resulting in nonreciprocity of absorption and stimulated emission cross sections," *IEEE J. Quantum Electron.*, vol. 18, no. 5, pp. 925-930, May 1982.
  - [41] N. P. Barnes and D. J. Gettemy, "Temperature variation of the refractive indices of yttrium lithium fluoride," *J. Opt. Soc. Am.*, vol. 70, no. 10, pp. 1244-1247, Oct. 1980.
  - [42] C. Görller-Walrand, and K. Binnemans, "Spectral intensities of f-f transitions," *Handbook on the physics and chemistry of rare earths*, vol. 25, pp.101-264, 1998.
  - [43] I. Razumova, A. Tkachuk, A. Nikitichev, and D. Mironov, "Spectral-luminescent properties of  $\text{Tm}:\text{YLF}$  crystal," *J. Alloy Compd.*, vol. 225, no. 1-2, pp. 129-132, July 1995.
  - [44] G. Armagan, A. M. Buoncrisiani, A. T. Inge, and B. Di Bartolo, "Comparison of spectroscopic properties of  $\text{Tm}$  and  $\text{Ho}$  in  $\text{YAG}$  and  $\text{YLF}$  crystals," in *Advanced Solid State Lasers, 18 March 1991, Hilton Head, South Carolina, United States: OSA Proceedings Series*, 1991, vol. 10, paper. MIL14.
  - [45] A. M. Tkachuk, I. K. Razumova, E. Y. Perlin, M. F. Joubert, and R. Moncorge, "Luminescence self-quenching in  $\text{Tm}^{3+}$ :YLF crystals: II. The luminescence decay and macrorates of energy transfer," *Opt. Spectr.*, vol. 90, no. 1, pp. 78-88, Jan. 2001.
  - [46] A. Braud, "Caractéristiques spectroscopiques et émission laser de l'ion  $\text{Tm}^{3+}$  à 1.5  $\mu\text{m}$  dans les fluorures," PhD thesis, Caen University, 1999 [In French].
  - [47] R. Souillard, M. Salhi, G. Brasse, P. Loiko, J.L. Doualan, L. Guillemot, A. Braud, A. Tyazhev, A. Hideur, and P. Camy, "Laser operation of highly-doped  $\text{Tm}:\text{LiYF}_4$  epitaxies: Towards thin-disk lasers," *Opt. Express*, vol. 27, no. 6, pp. 9287-9301, Mar. 2019.
  - [48] B. M. Walsh, N. P. Barnes, M. Petros, J. Yu, and U. N. Singh, "Spectroscopy and modeling of solid state lanthanide lasers: Application to trivalent  $\text{Tm}^{3+}$  and  $\text{Ho}^{3+}$  in  $\text{YLiF}_4$  and  $\text{LuLiF}_4$ ," *J. Appl. Phys.*, vol. 95, no. 7, pp. 3255-3271, Apr. 2004.
  - [49] P. Loiko, and M. Pollnau, "Stochastic model of energy-transfer processes among rare-earth ions. Example of  $\text{Al}_2\text{O}_3:\text{Tm}^{3+}$ ," *J. Phys. Chem. C*, vol. 120, no. 46, pp. 26480-26489, Nov. 2016.
  - [50] E. C. Honea, R. J. Beach, S. B. Sutton, J. A. Speth, S. C. Mitchell, J. A. Skidmore, M. A. Emanuel, and S. A. Payne, "115-W  $\text{Tm}:\text{YAG}$  diode-pumped solid-state laser," *IEEE J. Quantum Electron.*, vol. 33, no. 9, pp. 1592-1600, Sept. 1997.
  - [51] P. Loiko, P. Koopmann, X. Mateos, J. M. Serres, V. Jambunathan, A. Lucianetti, T. Mocek, M. Aguiló, F. Díaz, U. Griebner, V. Petrov, and C. Kränkel, "Highly-efficient, compact  $\text{Tm}^{3+}:\text{RE}_2\text{O}_3$  ( $\text{RE} = \text{Y}$ ,  $\text{Lu}$ ,  $\text{Sc}$ ) sesquioxide lasers based on thermal guiding," *IEEE J. Sel. Top. Quantum Electron.*, vol. 24, no. 5, pp. 1600713-1-13, Sept-Oct. 2018.
  - [52] X. Mateos, P. Loiko, J.M. Serres, K. Yumashev, U. Griebner, V. Petrov, M. Aguiló, and F. Díaz, "Efficient micro-lasers based on highly-doped monoclinic double tungstates," *IEEE J. Quantum Electron.*, vol. 53, no. 3, pp. 1700110, June 2017.
  - [53] M. Falconieri, A. Lanzi, G. Salvetti, and A. Toncelli, "Fluorescence dynamics in  $\text{Tm}, \text{Ho}:\text{YLF}$  following 800 nm pulsed laser excitation," *Appl. Phys. B*, vol. 66, no. 2, pp. 153-162, Feb. 1998.
  - [54] P. Loiko, R. Souillard, G. Brasse, J.L. Doualan, B. Guichardaz, A. Braud, A. Tyazhev, A. Hideur, and P. Camy, "Watt-level  $\text{Tm}:\text{LiYF}_4$  channel waveguide laser produced by diamond saw dicing," *Opt. Express*, vol. 26, no. 19, pp. 24653-24662, Sept. 2018.
  - [55] E. Y. Perlin, A. M. Tkachuk, M. F. Joubert, and R. Moncorge, "Cascade-avalanche up-conversion in  $\text{Tm}^{3+}$ :YLF crystals," *Opt. Spectr.*, vol. 90, no. 5, pp. 691-700, May 2001.
  - [56] D. Findlay, and R. A. Clay, "The measurement of internal losses in 4-level lasers," *Phys. Lett.*, vol. 20, no. 3, pp. 277-278, Feb. 1966.